

Synthesis of Kinetically Stabilized 1,2-Dihydrodisilenes

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Supporting Information

ABSTRACT: Kinetically stabilized 1,2-dihydrodisilenes were successfully synthesized and isolated by the introduction of sterically protecting bulky aryl groups. These 1,2-dihydrodisilenes exhibit distinct Si=Si double-bond character in both solution and the solid state. The Si-H bonds in these 1,2-dihydrodisilenes exhibit higher s character than those of typical σ^4 , λ^4 -hydrosilanes. Moderate heating of these 1,2-dihydrodisilenes in solution resulted in their isomerization to the corresponding trihydrodisilanes, with an intramolecular hydrogen migration as the rate-determining step.

• he high reactivity of the Si–H bond in σ^4 , λ^4 -hydrosilanes (R₃Si-H) and its versatility in organic and organometallic transformations have made these compounds one of the most attractive classes of chemical feed stock among organosilicon compounds.¹ However, the structurally closely related σ^3 , λ^4 hydrosilanes $R_E = Si(R) - H$ (E = main-group element) remain an exotic and underdeveloped class of hydrosilanes. The severely changed coordination environment around the silicon atom in σ^3 , λ^4 -hydrosilanes relative to that in σ^4 , λ^4 -hydrosilanes is expected to result in significant differences in the properties and reactivity of $\sigma^3_{,\lambda}^4$ -hydrosilanes. Only a few examples of σ^3 , λ^4 -hydrosilanes, such as mono- and dihydrosilenes² as well as monohydrodisilenes [e.g., lithiodisilene $R^{1}(H)Si=Si(Li)R^{1}(I)$ $(R^1 = Si(i-Pr)Dis_2$, Dis = CH $(SiMe_3)_2$)] have been reported to date.³ Despite the recent progress in the chemistry of kinetically stabilized multiply bonded silicon compounds, stable disilenes bearing more than one hydrogen substituent [e.g., 1,2dihydrodisilenes R(H)Si=Si(H)R]⁴ still remain elusive.⁵ Synthetically, the key challenge for the successful isolation of such multiply hydrogen-substituted disilenes lies in the effective stabilization of the sterically exposed H-Si=Si-H moiety. Wiberg et al.⁶ have suggested the intermediate formation of 1,2dihydrodisilene $R^{2}(H)Si=Si(H)R^{2}$ (II) ($R^{2} = SiH[Si(t Bu_{3}_{2}$ on the basis of NMR data of the crude reaction mixture. However, because of its facile thermal decomposition, II could not be isolated, and the structure of II was assigned by analysis of the decomposition product. Regardless of the

synthetic challenges involved, 1,2-dihydrodisilenes are desirable targets for two important reasons: (i) the H–Si=Si moiety is expected to exhibit characteristics distinctly different from those of σ^4 , λ^4 -hydrodisilanes [H–Si(R)₂–SiR₃], and (ii) the H–Si=Si–H moiety represents a powerful model for the parent disilene, H₂Si=SiH₂, allowing fundamental insights into the intrinsic nature of the bonding situation in H₂Si=SiH₂. The successful application of a variety of compounds containing low-coordinated heavier main-group elements⁷ prompted us to investigate their potential for the steric protection of the labile H–Si=Si–H moiety. Herein we report the synthesis, structure, spectroscopic properties, and thermal isomerization of kinetically stabilized 1,2-dihydrodisilenes 1a and 1b.

Scheme 1. Synthesis of 1,2-Dihydrodisilenes 1a and 1b

	LiNaph (2 eq.)	Ar H	CH(SiMe ₃) ₂
Aron br ₂ -	THF/Et ₂ O/hexane (2a THF/hexane (2b)	a) H Ar	CH(SiMe ₃) ₂
2a : Ar = Bbp 2b : Ar = Bbt	-110 °C	1a: Ar = Bbp (57%) 1b: Ar = Bbt (32%)	Bbp: R = H Bbt: R = C(SiMe ₃) ₃

Reduction of dibromosilanes 2a and 2b with 2 equiv of lithium naphthalenide (LiNaph) at -110 °C in THF/Et₂O/hexane (2a) or THF/hexane (2b) afforded 1,2-dihydrodisilenes 1a and 1b as pale-yellow solids in yields of 57 and 32%, respectively (Scheme 1). Both in the solid state and in solution (C₆D₆), 1a and 1b did not show any susceptibility toward decomposition below 25 °C.

Structural parameters of 1a in the solid state were determined by X-ray diffraction analysis (Figure 1a).⁸ Disilene 1a has a crystallographic center of symmetry at the middle of the Si–Si bond. Hydrogen atom H1 was located on the difference Fourier maps and refined isotropically. The Si–Si bond length in 1a [2.1708(6) Å] is contracted by 8% relative to that in the tetrahydrodisilane Bbp(H)₂Si–Si(H)₂Bbp (3) [2.3633(2) Å] and comparable to those in previously reported

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Figure 1. (a) Molecular structure of **1a**. Thermal displacement ellipsoids are drawn at the 50% probability level. H atoms except for H1 and H1* have been omitted for clarity. Selected bond lengths (Å) and angles (deg): Si1–Si1* = 2.1708(6), Si1–C1 = 1.8843(10), Si1–H1 = 1.45(2), Si1*–Si1–C1 = 126.87(4), C1–Si1–H1 = 114.5(9), H1–Si1–Si1* = 118.1(9), Si1*–Si1–C1–C2 = 81.85(9)°. (b) Experimental and calculated Si=Si bond lengths and *trans*-bent angles (θ) in **1a**.

disilenes (2.138-2.360 Å),⁹ indicating significant Si=Si double-bond character for 1a in the crystalline state. In addition, 1a exhibits a *trans*-bent structure, with a *trans*-bent angle (θ) of 6.3° around the Si1 atom. The molecular structure of 1a was reproduced by density functional theory (DFT) calculations,¹⁰ and the calculated Si1-Si1* bond length (2.157 Å) and *trans*-bent angle (2.9°) were in good agreement with those observed experimentally.

The ²⁹Si NMR spectra of 1a and 1b in C₆D₆ showed signals in the low-field region (1a, $\delta_{Si} = 63.3$ ppm; 1b, $\delta_{Si} = 61.8$ ppm), characteristic of disilenes with adjacent carbon substituents. In the ¹H NMR spectra of **1a** and **1b** (C_6D_6), the hydrogen nuclei attached to the low-coordinated silicon atoms resonated at 6.04 and 6.11 ppm respectively. Both these values are low-field shifted relative to those of σ^4 , λ^4 -hydrosilanes (e.g., $\delta_{\rm H} = 4.83$ ppm for 3 in C_6D_6), reflecting the magnetic anisotropy effect of the Si=Si π electrons.¹¹ The observed ${}^{1}J_{SiH}$ values of the H-Si=Si-H moieties in 1a (216 Hz) and 1b (210 Hz) are larger than those in σ^4 , λ^4 -hydrosilanes such as 3 (188 Hz), suggesting increased s character of the Si-H bonds. In contrast, previously reported hydrogen-substituted disilenes I and II exhibited much smaller ${}^{1}J_{SiH}$ values (I, 155 Hz; 3a II, 149.8 Hz⁶), suggesting a decrease in the s character of the Si-H bonds due to the presence of the electropositive silvl groups.¹² Similarly, the observed ${}^{2}J_{SiH}$ values for the H-Si=Si-H moieties in 1a (16 Hz) and 1b (16 Hz) were larger than those in 3 (6.5 Hz)and II (0.9 Hz), corroborating the increased s character of the Si-H bonds in 1a and 1b. Independently, natural bond orbital (NBO) calculations supported the greater s character of the Si-H bonds in **1a** $[\sigma_{SiH} = 0.6591Si(sp^{2.50}) + 0.7520H(s)]$ relative to those in **3** $[\sigma_{SiH} = 0.6557Si(sp^{3.12}) + 0.7550H(s)$ and $0.6506Si(sp^{3.20}) + 0.7594H(s)]$.¹⁰

The UV-vis spectra of 1a and 1b in hexane exhibited lowestenergy absorption maxima λ_{max} at 411 nm ($\varepsilon = 2.1 \times 10^4 \text{ M}^{-1} \text{ cm}^{-1}$) and 421 nm ($\varepsilon = 2.0 \times 10^4 \text{ M}^{-1} \text{ cm}^{-1}$) respectively, which can be assigned to $\pi - \pi^*$ electron transitions in the Si= Si moiety. The almost identical λ_{max} values for 1a (412 nm) and 1b (423 nm) in THF would exclude coordination of THF to these disilenes. In the solid-state Raman spectra, 1a and 1b exhibited Raman lines at 566 and 575 cm⁻¹, respectively. Theoretical calculations for 1a estimated the Si=Si vibrational frequency to be 588 cm⁻¹,¹⁰ which is in good agreement with the experimentally observed values. The Si=Si stretching frequencies for previously reported carbon-substituted disilenes are known to be observed in the range from 500 to 600 cm⁻¹,¹³ indicating that **1a** and **1b** contain distinct Si=Si double bonds in the solid state. The IR spectra of **1a** and **1b** in a KBr disk showed Si-H vibrational frequencies at $\nu_{\text{SiH}} = 2160 \text{ cm}^{-1}$ (**1a**) and 2151 cm⁻¹ (**1b**). The observed values are again in good conformity with the calculated value for **1a** (2168 cm⁻¹) and slightly larger than those for σ^4 , λ^4 -hydrosilanes (e.g., 2122 cm⁻¹ for Ph₃SiH).^{2a}

Moderate heating of solutions of 1a and 1b in C_6D_6 to 80 °C resulted in the isomerization of these disilenes into the corresponding disilanes 4a and 4b (Scheme 2).¹⁴ The formation of 4a and 4b can be logically explained by a mechanism proceeding via an initial 1,2-hydrogen migration to form intermediate silylsilylenes 5a and 5b, followed by a subsequent insertion of the silylene moiety into the benzylic C–H bonds of the sterically demanding CH(SiMe₃)₂ groups.¹⁵ A similar mechanism was proposed for the decomposition of transient disilene II.^{6,16}

Scheme 2. Thermolysis of 1a and 1b



Kinetic studies of the thermolysis of 1b in hexane or THF by UV-vis spectrometry revealed that the isomerization is a firstorder, unimolecular reaction. For hexane solutions, the activation parameters ΔH^{\ddagger} and ΔS^{\ddagger} were estimated to be 20.6(5) kcal mol⁻¹ and -15(2) cal K⁻¹ mol⁻¹. The negative value of ΔS^{\ddagger} indicates a considerable conformational change of 1b during the rate-determining step. For THF solutions, the activation parameters were determined to be $\Delta H^{\ddagger} = 23.6(7)$ kcal mol⁻¹ and $\Delta S^{\ddagger} = -6(2)$ cal K⁻¹ mol⁻¹. The small negative value of ΔS^{\ddagger} does not support any involvement of THF molecules during the rate-determining step. The isomerization mechanism of 1b was further investigated using DFT calculations. $^{10}\ \mbox{Figure 2}\ \mbox{shows the computationally generated}$ energy profile for the thermal isomerization of 1b. The terminal hydrogen atom H2 in 1b initially moves via transition state TS1 toward a bridging position above the Si=Si π plane, resulting in the formation of intermediate 6b. The calculated activation parameters for this step ($\Delta H^{\ddagger} = 19.4 \text{ kcal mol}^{-1}$, $\Delta S^{\ddagger} = -2.4$ cal K^{-1} mol⁻¹) are in close agreement with the experimentally estimated values, suggesting that this step is rate-determining. Although the transition state between 6b and 5b (TS2) could not be located, the necessary activation barrier was estimated to be sufficiently low to allow fast interconversion between 5b and **6b** prior to the intramolecular cyclization.^{17,18} The final step $(5b \rightarrow 4b)$ proceeds via TS3 with a large exothermicity (-36.2 kcal mol^{-1}), suggesting that the isomerization from 1b to 4b should proceed readily. The activation barrier for this step $(\Delta H^{\ddagger} = 16.3 \text{ kcal mol}^{-1})$ was found to be smaller than that for the first step. Moreover, the activation entropy of this step was



Figure 2. Calculated reaction path for the isomerization of **1b**. Values beneath the energy levels represent the SCF energies relative to **1b** (in kcal mol⁻¹); $\mathbf{R} = \text{SiMe}_3$. The activation parameters in the boxes were calculated with zero-point vibrational energy corrections.

calculated to be close to zero $(-0.06 \text{ cal } \text{K}^{-1} \text{ mol}^{-1})$, suggesting that this final step, intramolecular cyclization, is not the experimentally observed rate-determining step. In conclusion, the computational results support the assumption that a gradual isomerization of 1,2-dihydrodisilenes **1a** and **1b** via a 1,2-hydrogen shift is what was observed in solution.

In summary, we have reported the synthesis, structure, and spectroscopic properties of kinetically stabilized 1,2-dihydrodisilenes 1a and 1b. Both in the solid state and in solution, 1a and 1b retain a pronounced Si=Si double bond, and their Si-H bonds have higher s character than those of σ^4 , λ^4 -hydrosilanes. Heating 1a and 1b resulted in isomerizations via intramolecular hydrogen migrations, resembling the hydrogen-shift equilibrium suggested for the parent disilene H₂Si=SiH₂.¹⁸

ASSOCIATED CONTENT

S Supporting Information

Experimental procedures, analytical data for new compounds, computational results, and X-ray crystallographic data (CIF). This material is available free of charge via the Internet at http://pubs.acs.org.

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Notes

The authors declare no competing financial interest.

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(8) The Si–Si bond length of **1b** was estimated to be in the range of 2.16-2.18 Å on the basis of a preliminary X-ray crystallographic analysis.

(9) The range of the Si=Si bond lengths of disilenes was taken from the Cambridge Crystallographic Data Centre database (82 examples).
(10) These calculations were performed at the B3PW91/6-311+G(2df)[Si]:6-31G(d)[C,H] level of theory.

(11) The calculated ²⁹Si and ¹H chemical shifts of **1a** and **1b** (δ_{Si} = 72.6 ppm, δ_{H} = 6.06 ppm for **1a**; δ_{Si} = 66.7, 68.7 ppm, δ_{H} = 6.27, 6.28 ppm for **1b**) were comparable to the experimentally observed values (HCTH407/6-311+G(2df)[Si]:6-31G(d)[C,H]). For Gauge-Independent Atomic Orbital (GIAO) calculations on disilenes, see: Karni, M.; Apeloig, Y.; Takagi, N.; Nagase, S. *Organometallics* **2005**, *24*, 6319.

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(14) Thermolysis of **1a** afforded small amount of unidentified byproducts, resulting in a moderate yield of **4a**, while disilene **1b** isomerized quantitatively to **4b**.

(15) A transient silylene Tbt(Mes)Si: (Tbt = 2,4,6-tris[bis(trime-thylsilyl)methyl]phenyl) undergoes facile cyclization in a fashion similar to that of **5b**. See: Suzuki, H.; Tokitoh, N.; Okazaki, R.; Harada, J.; Ogawa, K.; Tomoda, S.; Goto, M. *Organometallics* **1995**, *14*, 1016.

(16) Although a direct pathway from disilene 1 to cyclic disilane 4 via a [1,5]-H shift of the benzylic proton along with intramolecular cyclization (as in the case of Mes₂Si=SiMes₂) can be proposed for the isomerization of 1, the mechanism shown here is considered to be the most reasonable because the results of the theoretical calculations reproduced well those obtained in the experimental kinetic study. See: (a) Nguyen, T.-L.; Scheschkewitz, D. J. Am. Chem. Soc. 2005, 127,

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(17) As for the isomerization of model disilenes R(H)Si=Si(H)R (R = H, Me, *t*-Bu), transition states corresponding to **TS2** were found in the DFT calculations, and the activation barrier was estimated to be <1 kcal mol⁻¹. See the Supporting Information for details.

(18) The isomerization among 1b, 6b, and 5b resembles the hydrogen-shift equilibrium of the parent disilene $H_2Si=SiH_2$. See: (a) Trinquier, G. J. Am. Chem. Soc. 1990, 112, 2130. (b) Dolgonos, G. Chem. Phys. Lett. 2008, 466, 11. (c) Sari, L.; McCarthy, M. C.; Schaefer, H. F. III; Thaddeus, P. J. Am. Chem. Soc. 2003, 125, 11409.